

### **NCE N-Channel Super Trench Power MOSFET**

### **Description**

The NCEP40T13AGU uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

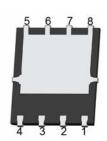
### **General Features**

- $V_{DS}$  =40V, $I_D$  =130A  $R_{DS(ON)}$ =1.8m $\Omega$  (typical) @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

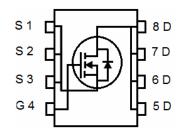
### **DFN 5X6**





**Top View** 

**Bottom View** 



**Schematic Diagram** 

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P40T13AGU	NCEP40T13AGU	DFN5X6-8L	-	-	-

### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>G</sub> S	±20	V
Drain Current-Continuous (Silicon Limited)	I <sub>D</sub>	130	Α
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	100	Α
Pulsed Drain Current (Package Limited)	I <sub>DM</sub>	400	Α
Maximum Power Dissipation	P <sub>D</sub>	130	W
Derating factor		1.04	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	480	mJ
Operating Junction and Storage Temperature Range	$T_J,T_STG$	-55 To 150	$^{\circ}$ C

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>0JC</sub> 0.96	°C/W
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# NCEP40T13AGU

## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

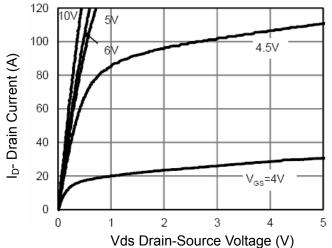
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u> </u>					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	40		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics (Note 3)	<u> </u>		•	•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	2.8	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =65A	-	1.8	2.0	mΩ
Forward Transconductance	<b>g</b> Fs	V <sub>DS</sub> =5V,I <sub>D</sub> =65A		60	-	S
Dynamic Characteristics (Note4)	<u> </u>		•	•		
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =20V,V <sub>GS</sub> =0V,	-	2100	-	PF
Output Capacitance	C <sub>oss</sub>		-	500	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	39	-	PF
Switching Characteristics (Note 4)	<u> </u>		•	•		
Turn-on Delay Time	t <sub>d(on)</sub>		-	8	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =20 $V$ , $I_D$ =65 $A$	-	3	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_G$ =1.6 $\Omega$	-	26	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	\/ 00\/ L 05A	-	28		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =20V, $I_{D}$ =65A, $V_{GS}$ =10V	-	8		nC
Gate-Drain Charge	Q <sub>gd</sub>		-	4		nC
Drain-Source Diode Characteristics	<u> </u>		•	•		
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =65A	-		1.2	V
Diode Forward Current	Is		-	-	130	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C$ , $I_F = I_S$	-		23	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-		62	nC

### Notes:

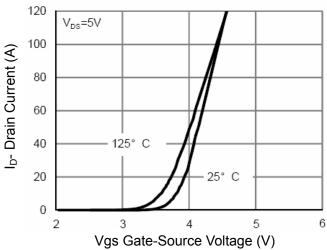
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\!\!\mathrm{C}$  ,V  $_{DD}$  =20 V,V  $_{G}$  =10 V,L=0.5 mH,Rg=25  $\Omega$



### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

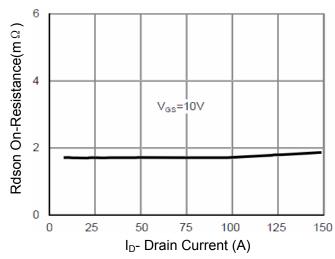


Figure 3 Rdson- Drain Current

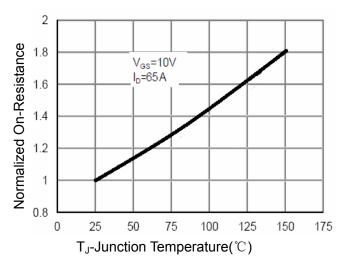


Figure 4 Rdson-JunctionTemperature

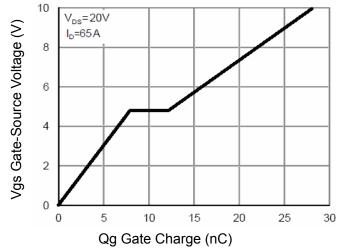


Figure 5 Gate Charge

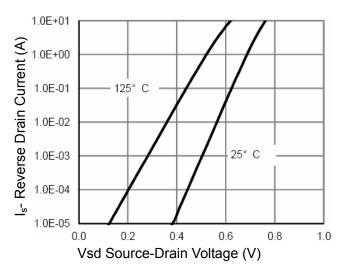


Figure 6 Source- Drain Diode Forward



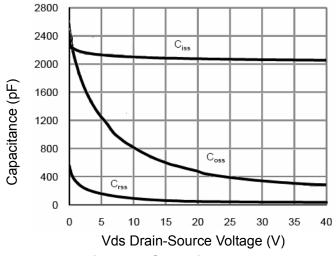


Figure 7 Capacitance vs Vds

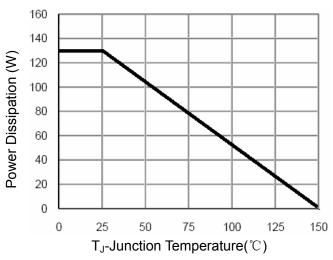
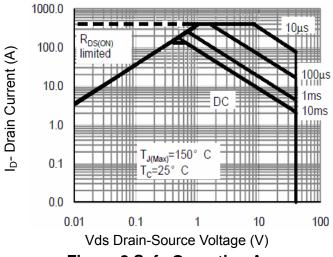


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

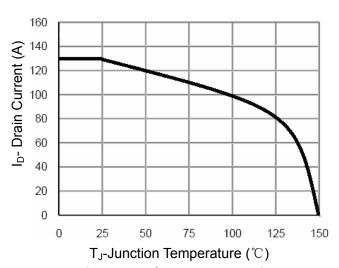
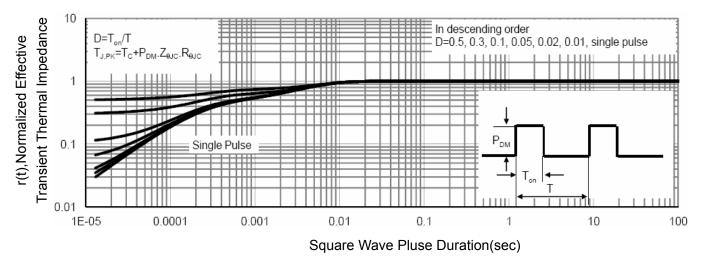


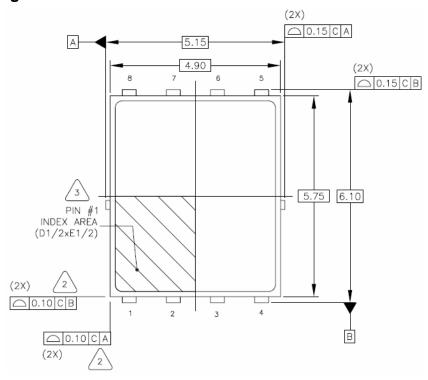
Figure 10 Current De-rating

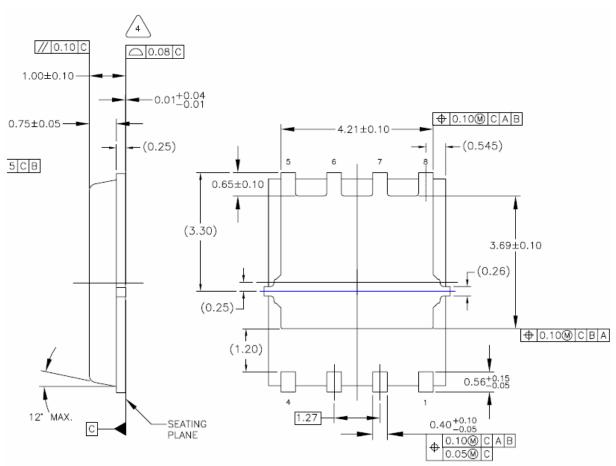


**Figure 11 Normalized Maximum Transient Thermal Impedance** 



### **DFN5X6-8L Package Information**





### http://www.ncepower.com

# NCEP40T13AGU

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